

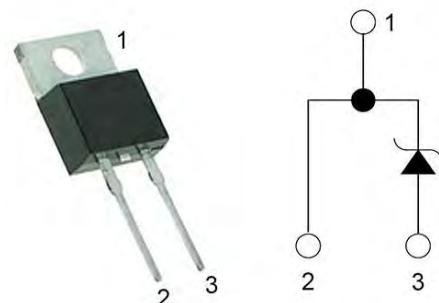


## Features

- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on  $V_F$
- Temperature Independent Switching Behavior

$V_R = 650 \text{ V}$   
 $I_F = 10\text{A} (\text{T}_C=150^\circ\text{C})$   
 $Q_c = 23\text{nC} (V_R=400\text{V})$

TO-220-2L



## Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- Higher Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

## Applications

- Motor Drives
- Solar
- AC/DC Converters
- DC/DC Converters
- Uninterruptable Power Supplies

## Maximum Ratings ( $\text{T}_C=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$		650	V
Peak Reverse Surge Voltage	$V_{RSM}$		650	V
DC Blocking Voltage	$V_R$		650	V
Continuous Forward Current	$I_F$	$\text{T}_C=25^\circ\text{C}$ $\text{T}_C=135^\circ\text{C}$ $\text{T}_C=150^\circ\text{C}$	32 14 10	A
Non repetitive Forward Surge Current	$I_{FSM}$	$\text{T}_C = 25^\circ\text{C}, t_p=10 \text{ ms},$ Half Sine Pulse $\text{T}_C = 150^\circ\text{C}, t_p=10 \text{ ms},$ Half Sine Pulse $\text{T}_C = 25^\circ\text{C}, t_p=10 \mu\text{s},$ Square	65 55 520	A
Repetitive peak Forward Surge Current	$I_{FRM}$	$\text{T}_C = 25^\circ\text{C}, t_p=10 \text{ ms},$ Freq = 0.1Hz, 100 cycles, Half Sine Pulse $\text{T}_C = 150^\circ\text{C}, t_p=10 \text{ ms},$ Freq = 0.1Hz, 100 cycles, Half Sine Pulse	55 45	A
Total power dissipation	$P_D$	$\text{T}_C=25^\circ\text{C}$	94	W
Operating Junction Temperature	$T_J$		-55 to 175	°C
Storage Temperature	$T_{STG}$		-55 to 175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



## Electrical Characteristics

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	$V_{DC}$	$I_R = 250\mu A, T_J = 25^\circ C$	650			V
Forward Voltage	$V_F$	$I_F = 10A, T_J = 25^\circ C$		1.45	1.8	V
		$I_F = 10A, T_J = 125^\circ C$		1.6		
		$I_F = 10A, T_J = 175^\circ C$		1.7		V
Reverse Current	$I_R$	$V_R = 650V, T_J = 25^\circ C$		12	80	uA
		$V_R = 650V, T_J = 125^\circ C$		68		uA
		$V_R = 650V, T_J = 175^\circ C$		190		uA
Total Capacitive Charge	$Q_C$	$V_R = 400V$ $T_J = 25^\circ C$		23		nC
Total Capacitance	C	$V_R = 1V, T_J = 25^\circ C,$ Freq = 1MHz		380		pF
		$V_R = 200V, T_J = 25^\circ C,$ Freq = 1MHz		48		
		$V_R = 400V, T_J = 25^\circ C,$ Freq = 1MHz		31		

Note: This is a majority carrier diode, so there is no reverse recovery charge

## Thermal Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		1.6		°C/W



## Typical Electrical Curves

**LGE3D10065A**

Silicon Carbide Schottky Diode



Figure 1. Forward Characteristics

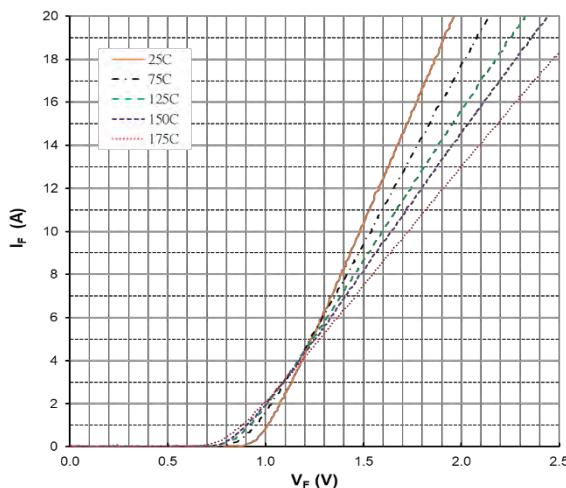


Figure 2. Forward Characteristics

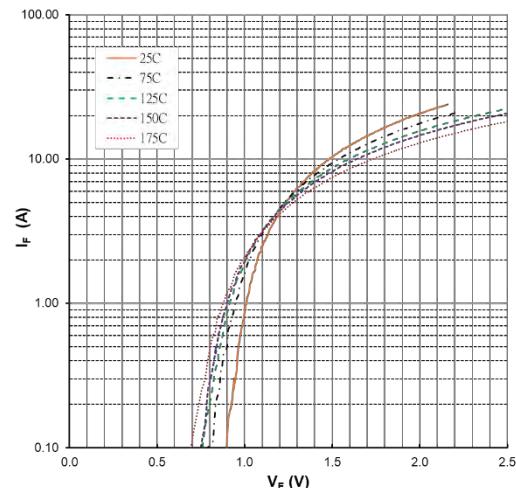


Figure 3. Reverse Characteristics

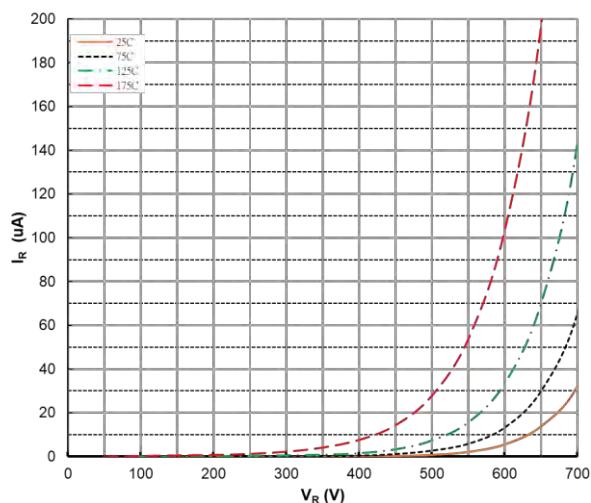


Figure 4. Power Derating

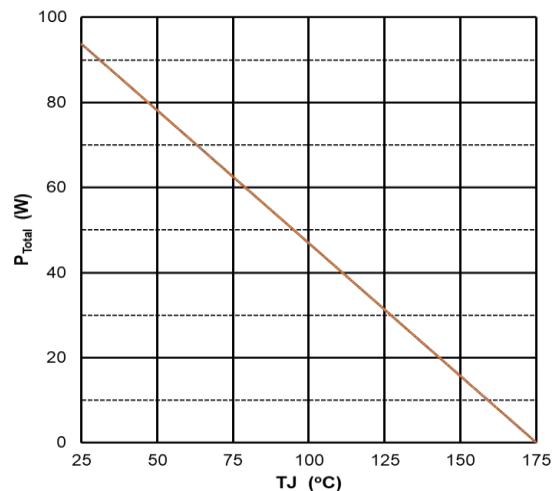


Figure 5. Capacitance vs Reverse Voltage

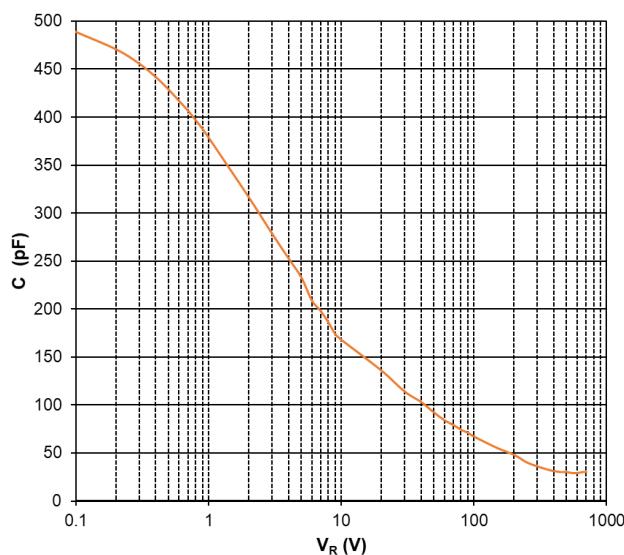
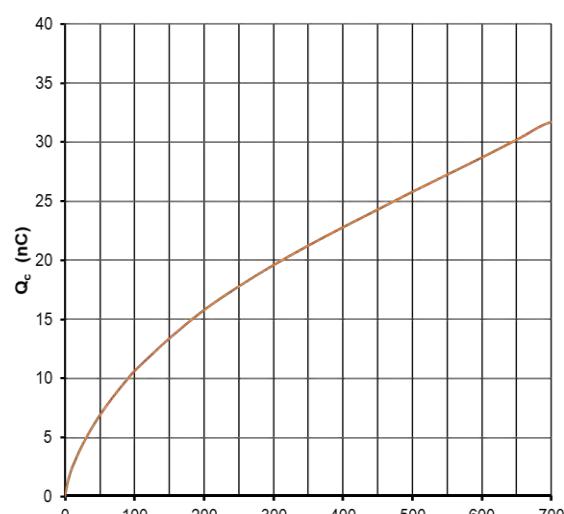


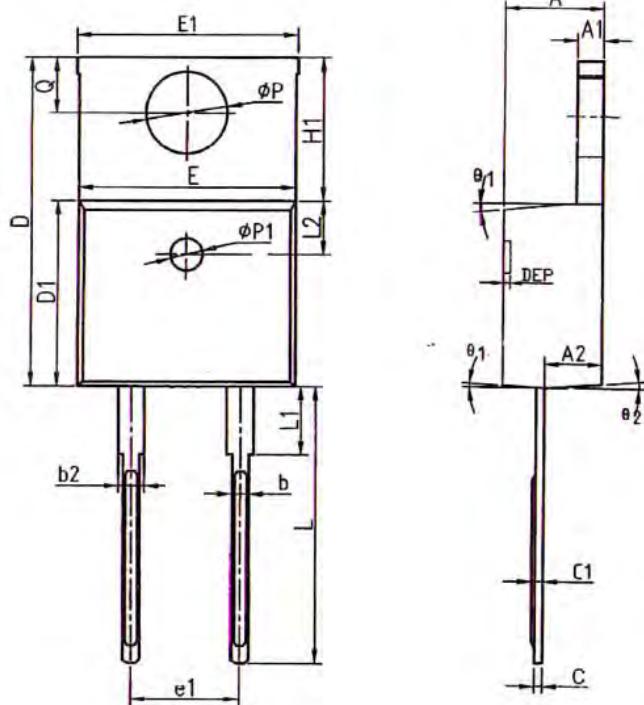
Figure 6. Recovery Charge vs Reverse Voltage





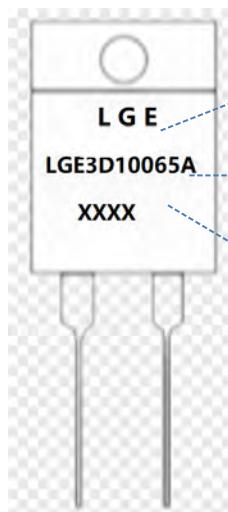
## Package Dimensions

(TO-220-2L Package)



SYMBOL	COMMON DIMENSIONS			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	4.40	4.57	4.70	0.173	0.180	0.185
A1	1.22	1.27	1.32	0.048	0.050	0.052
A2	2.59	2.69	2.79	0.102	0.106	0.110
b	0.77	0.813	0.90	0.030	0.032	0.035
b2	1.20	1.27	1.36	0.047	0.050	0.054
c	0.34	0.381	0.47	0.013	0.015	0.019
c1	0.40	0.559	0.60	0.016	0.022	0.024
D	14.70	15.00	15.30	0.579	0.591	0.602
D1	8.60	8.70	8.80	0.339	0.343	0.346
E	10.06	10.16	10.26	0.396	0.400	0.404
E1	10.10	10.25	10.35	0.398	0.404	0.407
E2	10.00	10.10	10.20	0.394	0.398	0.402
e	2.54 BSC			0.100 BSC		
e1	5.08 BSC			0.200 BSC		
H1	6.10	6.30	6.50	0.240	0.248	0.256
L	13.20	13.40	13.50	0.520	0.528	0.531
L1	-	3.75	4.00	-	0.148	0.157
L2	2.50 REF			0.098 REF		
φP	3.76	3.84	3.88	0.148	0.151	0.153
Q	2.60	2.743	2.90	0.102	0.108	0.114
θ1	5°	7°	9°	5°	7°	9°
θ2	1°	3°	5°	1°	3°	5°
ΦP1	1.40	1.50	1.60	0.055	0.059	0.063
DEP	0.05	0.10	0.20	0.002	0.004	0.008

Part Number	Package	Packing	Marking	M.O.Q
LGE3D10065A	TO-220-2L	50pcs / Tube	LGE3D10065A	500



Company LOGO

Part No.

4-6 digits: Traceable code

Package	Packing	Box Size L×W×H(mm)	Quatity(pcs/box)	Carton Size L×W×H(mm)	Quatity(pcs/carton)
TO-220-2L	50pcs/Tube	558×148×38	1000	565×225×175	5000